



DMN3112SQ

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	I _D Max T _A = +25°C
30V	57mΩ @ V _{GS} = 10V	5.8A
	112mΩ @ V _{GS} = 4.5V	2.5A

Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- · General Purpose Interfacing Switch
- Power Management Functions
- Boost Application
- Analog Switch

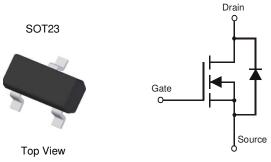
Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN3112SQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

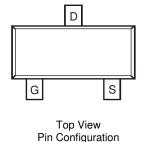
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed Over Copper Leadframe. Solderable per MIL-STD-202, Method 208 © 3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Equivalent Circuit



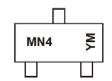
Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
DMN3112SQ-7	Automotive	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



MN4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021)

M = Month (ex: 9 = September)

Date Code Key

Date Code Ney											
Year	2014	 2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	В	 ı	J	K	L	М	N	0	Р	R	S

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain Source Voltage		V _{DSS}	30	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 5)	T _A = +25°C T _A = +70°C	lo	5.8 4.2	А
Drain Current (Note 5)	Pulsed	I _{DM}	20	Α
Body-Diode Continuous Current (Note 5)		Is	2.0	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.4	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	Reja	90	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

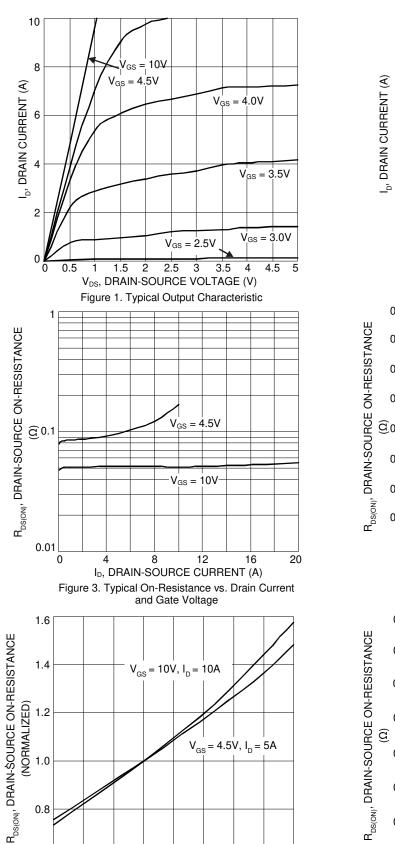
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)	1		•	•		
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	Vgs = 0V, ID = 250µA
Zero Gate Voltage Drain Current	I _{DSS}	_		800	nA	$V_{DS} = 30V$, $V_{GS} = 0V$
Gate-Body Leakage	I _{GSS}	_	_	±80 ±800	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$ $V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(TH)}	1.3	1.9	2.2	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	RDS(ON)	_	47 92	57 112	mΩ	V _{GS} = 10V, I _D = 5.8A V _{GS} = 4.5V, I _D = 4.2A
Forward Transconductance	Yfs	_	4.7	_	S	$V_{DS} = 5V, I_{D} = 4.2A$
Source-Drain Diode Forward Voltage	VsD	_	0.78	1.1	V	Vgs = 0V, Is = 2.0A
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss		268	_	pF	
Output Capacitance	Coss	_	73	_	pF	V _{DS} = 5V, V _{GS} = 0V - f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	50	_	pF	7 - 1.0IVII IZ

Notes:

- 5. Device mounted on FR-4 PCB. t ≤5 sec. 6. Short duration pulse test used to minimize self-heating effect.
- 7. Guaranteed by design. Not subject to production testing.





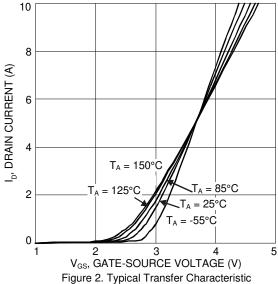
 $T_{A}, \, \text{AMBIENT TEMPERATURE (°C)} \\ \text{Figure 5. On-Resistance Variation with Temperature} \\$

50

75

100

125 150



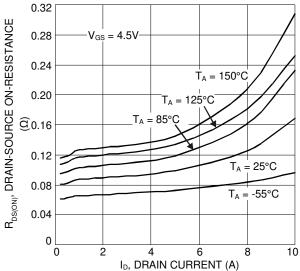


Figure 4. Typical On-Resistance vs. Drain Current and Temperature

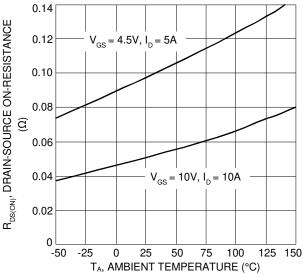


Figure 6. On-Resistance Variation with Temperature

0

25

0.6

-50 -25



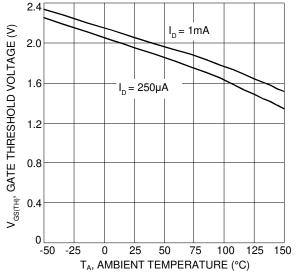
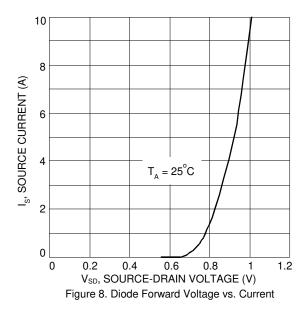
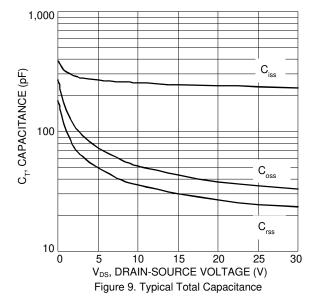


Figure 7. Gate Threshold Variation vs. Ambient Temperature





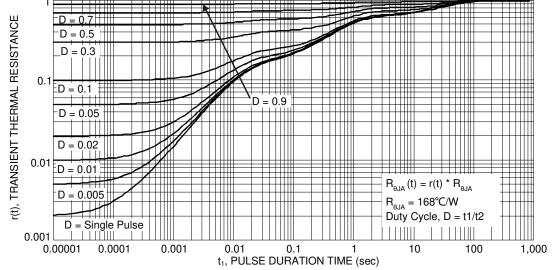


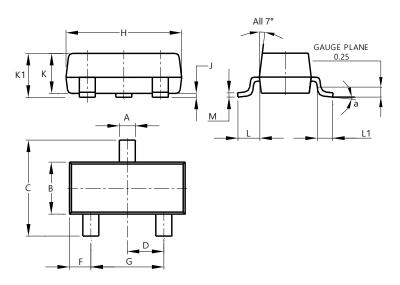
Figure 10. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

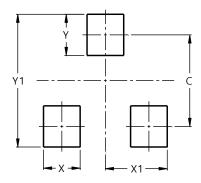


	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
Y1	2.9



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